Power MOSFET 170 mAmps, 100 Volts

N-Channel SOT-23

Features

- BVSS Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	100	Vdc
Gate–Source Voltage – Continuous – Non–repetitive ($t_p \le 50 \mu s$)	V _{GS} V _{GSM}	±20 ±40	Vdc Vpk
Drain Current - Continuous (Note 1) - Pulsed (Note 2)	I _D	0.17 0.68	Adc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 3) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

- 1. The Power Dissipation of the package may result in a lower continuous drain current.
- 2. Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.
- 3. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

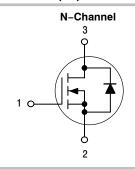


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170 mAMPS 100 VOLTS

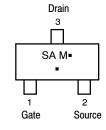
 $R_{DS(on)} = 6 \Omega$



MARKING DIAGRAM & PIN ASSIGNMENT



SOT-23 CASE 318 STYLE 21



SA = Device Code M = Date Code

= Pb-Free Package

(*Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Charac	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS		•	•		•	•
Drain-Source Breakdown Voltage (V _{GS} = 0, I _D = 250 μAdc)		V _{(BR)DSS}	100	_	-	Vdc
Zero Gate Voltage Drain Current $(V_{GS}=0,V_{DS}=100\text{Vdc}) \qquad T_J=25^\circ\text{C} \\ T_J=125^\circ\text{C}$	I _{DSS}	- -	_ _	15 60	μAdc	
Gate-Body Leakage Current (V _{GS} = 20 Vdc, V _{DS} = 0)	I _{GSS}	-	-	50	nAdc	
ON CHARACTERISTICS (Note 4)		-			•	•
Gate Threshold Voltage (V _{DS} = V _{GS} , I _D = 1.0 mAdc)			1.6	-	2.6	Vdc
Static Drain–Source On–Resistance (V _{GS} = 10 Vdc, I _D = 100 mAdc)			-	-	6.0	Ω
Forward Transconductance (V _{DS} = 25 Vdc, I _D = 100 mAdc)	9fs	80	-	-	mmhos	
DYNAMIC CHARACTERISTICS		•	•			•
Input Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)		C _{iss}	_	20	_	pF
Output Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)		C _{oss}	-	9.0	-	pF
Reverse Transfer Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)	C _{rss}	-	4.0	-	pF	
SWITCHING CHARACTERISTICS ⁽⁴⁾		<u>.</u>				
Turn-On Delay Time	(V _{CC} = 30 Vdc, I _C = 0.28 Adc,	t _{d(on)}	_	20	_	ns
Turn-Off Delay Time	V_{GS} = 10 Vdc, R_{GS} = 50 Ω)	t _{d(off)}	-	40	-	ns
REVERSE DIODE		<u>.</u>				
Diode Forward On-Voltage (I _D = 0.34 Adc, V _{GS} = 0 Vdc)		V _{SD}	_	_	1.3	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Device	Package	Shipping [†]
BSS123LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
BSS123LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
BVSS123LT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{4.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

^{*}BVSS Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

TYPICAL ELECTRICAL CHARACTERISTICS

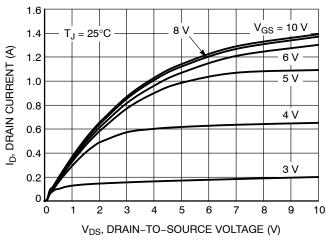


Figure 1. On-Region Characteristics

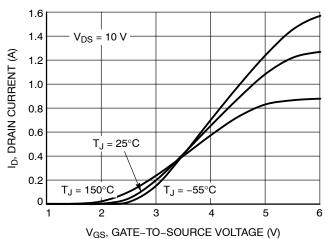


Figure 2. Transfer Characteristics

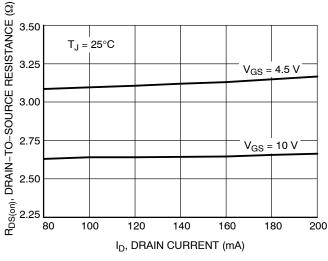


Figure 3. On–Resistance vs. Drain Current and Gate Voltage

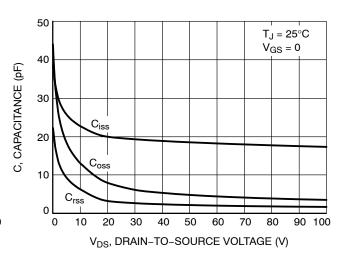


Figure 4. Capacitance Variation

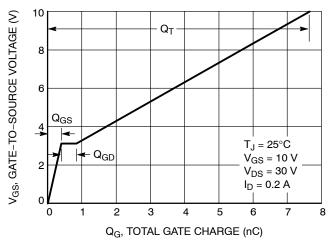


Figure 5. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

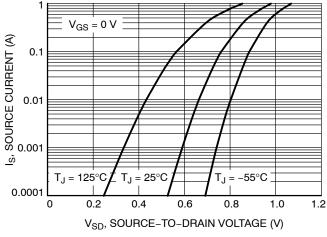


Figure 6. Diode Forward Voltage vs. Current

TYPICAL ELECTRICAL CHARACTERISTICS

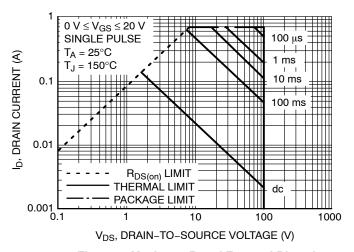


Figure 7. Maximum Rated Forward Biased Safe Operating Area

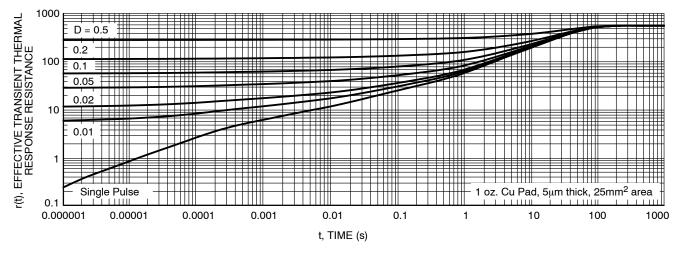
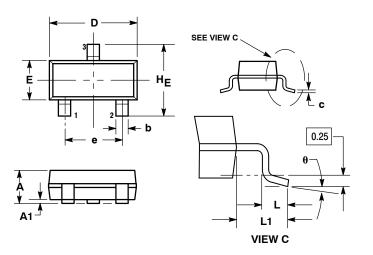


Figure 8. Thermal Response

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AP**



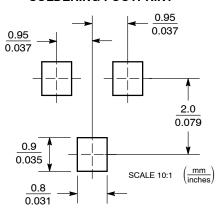
NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°		10°	0°		10°

- STYLE 21: PIN 1. GATE 2. SOUR
 - SOURCE
 - 3. DRAIN

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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